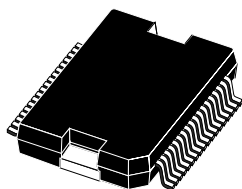
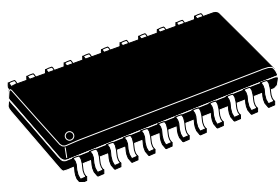


## DMOS dual full bridge driver

Datasheet - production data

**PowerSO36****SO24**  
(20 + 2 + 2)**Ordering numbers:****L6206PD (PowerSO36)**  
**L6206D (SO24)**

- Thermal shutdown
- Undervoltage lockout
- Integrated fast freewheeling diodes

### Applications

- Bipolar stepper motor
- Dual or quad DC motor

### Description

The L6206 device is a DMOS dual full bridge designed for motor control applications, realized in BCD technology, which combines isolated DMOS power transistors with CMOS and bipolar circuits on the same chip. Available in the PowerSO36 and SO24 (20 + 2 + 2) packages, the L6206 device features thermal shutdown and a non-dissipative overcurrent detection on the high-side power MOSFETs plus a diagnostic output that can be easily used to implement the overcurrent protection.

### Features

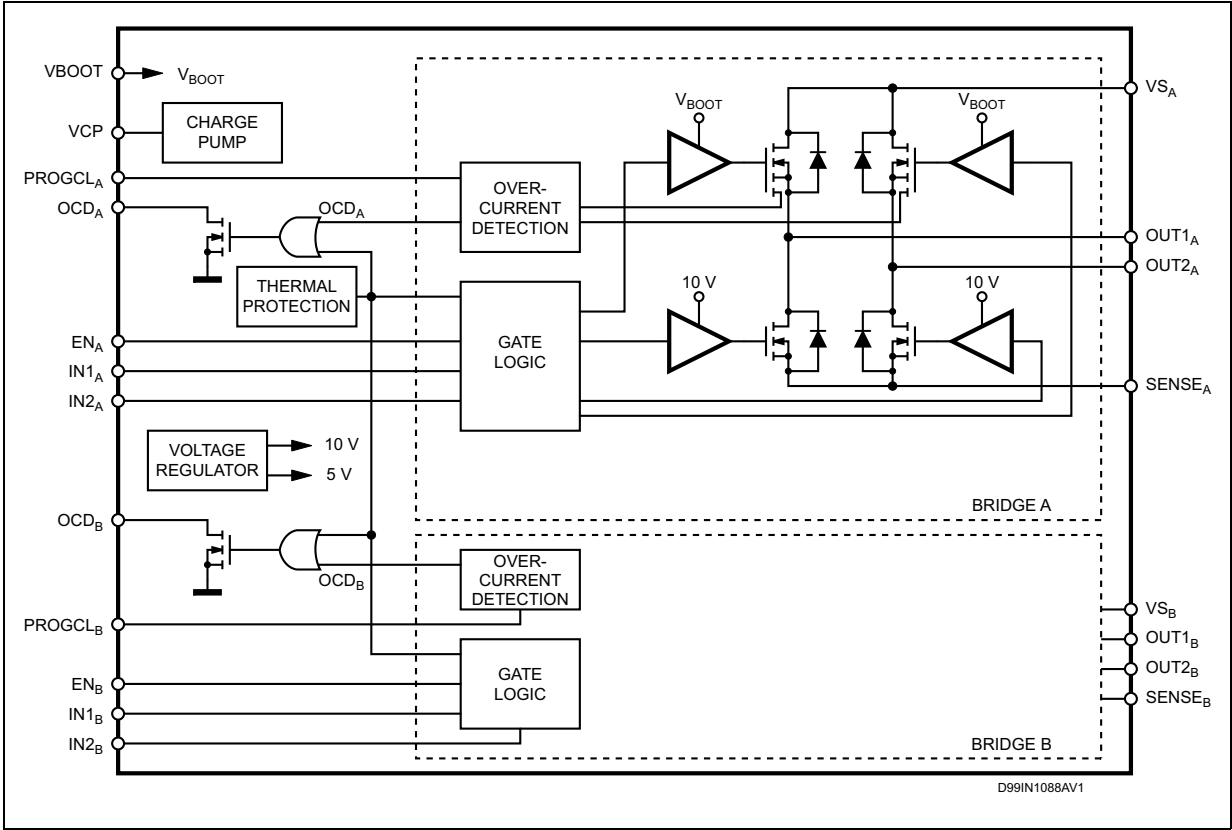
- Operating supply voltage from 8 to 52 V
- 5.6 A output peak current (2.8 A DC)
- $R_{DS(ON)}$  0.3  $\Omega$  typ. value at  $T_j = 25^\circ\text{C}$
- Operating frequency up to 100 KHz
- Programmable high-side overcurrent detection and protection
- Diagnostic output
- Paralleled operation
- Cross conduction protection

# Contents

|          |                                                      |           |
|----------|------------------------------------------------------|-----------|
| <b>1</b> | <b>Block diagram</b>                                 | <b>3</b>  |
| <b>2</b> | <b>Maximum ratings</b>                               | <b>4</b>  |
| <b>3</b> | <b>Pin connections</b>                               | <b>6</b>  |
| <b>4</b> | <b>Electrical characteristics</b>                    | <b>8</b>  |
| <b>5</b> | <b>Circuit description</b>                           | <b>11</b> |
| 5.1      | Power stages and charge pump                         | 11        |
| 5.2      | Logic inputs                                         | 12        |
| 5.3      | Non-dissipative overcurrent detection and protection | 13        |
| 5.4      | Thermal protection                                   | 16        |
| <b>6</b> | <b>Application information</b>                       | <b>17</b> |
| 6.1      | Paralleled operation                                 | 18        |
| 6.2      | Output current capability and IC power dissipation   | 21        |
| 6.3      | Thermal management                                   | 22        |
| <b>7</b> | <b>Package information</b>                           | <b>25</b> |
| 7.1      | PowerSO36 package information                        | 25        |
| 7.2      | SO24 package information                             | 27        |
| <b>8</b> | <b>Revision history</b>                              | <b>28</b> |

1 Block diagram

Figure 1. Block diagram



## 2 Maximum ratings

**Table 1. Absolute maximum ratings**

| Symbol                         | Parameter                                                                                                          | Test conditions                                                                   | Value       | Unit |
|--------------------------------|--------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|-------------|------|
| $V_S$                          | Supply voltage                                                                                                     | $V_{SA} = V_{SB} = V_S$                                                           | 60          | V    |
| $V_{OD}$                       | Differential voltage between $VS_A$ , $OUT1_A$ , $OUT2_A$ , $SENSE_A$ and $VS_B$ , $OUT1_B$ , $OUT2_B$ , $SENSE_B$ | $V_{SA} = V_{SB} = V_S = 60\text{ V}$ ;<br>$V_{SENSEA} = V_{SENSEB} = \text{GND}$ | 60          | V    |
| $OCD_A, OCD_B$                 | OCD pins voltage range                                                                                             | -                                                                                 | -0.3 to +10 | V    |
| $PROGCL_A$ ,<br>$PROGCL_B$     | PROGCL pins voltage range                                                                                          | -                                                                                 | -0.3 to +7  | V    |
| $V_{BOOT}$                     | Bootstrap peak voltage                                                                                             | $V_{SA} = V_{SB} = V_S$                                                           | $V_S + 10$  | V    |
| $V_{IN}$ , $V_{EN}$            | Input and enable voltage range                                                                                     | -                                                                                 | -0.3 to +7  | V    |
| $V_{SENSEA}$ ,<br>$V_{SENSEB}$ | Voltage range at pins $SENSE_A$ and $SENSE_B$                                                                      | -                                                                                 | -1 to +4    | V    |
| $I_{S(\text{peak})}$           | Pulsed supply current (for each $V_S$ pin), internally limited by the overcurrent protection                       | $V_{SA} = V_{SB} = V_S$ ;<br>$t_{PULSE} < 1\text{ ms}$                            | 7.1         | A    |
| $I_S$                          | RMS supply current (for each $V_S$ pin)                                                                            | $V_{SA} = V_{SB} = V_S$                                                           | 2.8         | A    |
| $T_{stg}$ , $T_{OP}$           | Storage and operating temperature range                                                                            | -                                                                                 | -40 to 150  | °C   |

**Table 2. Recommended operating conditions**

| Symbol                         | Parameter                                                                                                          | Test conditions                                        | Min.     | Max.   | Unit   |
|--------------------------------|--------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------|----------|--------|--------|
| $V_S$                          | Supply voltage                                                                                                     | $V_{SA} = V_{SB} = V_S$                                | 8        | 52     | V      |
| $V_{OD}$                       | Differential voltage between $VS_A$ , $OUT1_A$ , $OUT2_A$ , $SENSE_A$ and $VS_B$ , $OUT1_B$ , $OUT2_B$ , $SENSE_B$ | $V_{SA} = V_{SB} = V_S$ ;<br>$V_{SENSEA} = V_{SENSEB}$ | -        | 52     | V      |
| $V_{SENSEA}$ ,<br>$V_{SENSEB}$ | Voltage range at pins $SENSE_A$ and $SENSE_B$                                                                      | (pulsed $t_W < t_{rr}$ )<br>(DC)                       | -6<br>-1 | 6<br>1 | V<br>V |
| $I_{OUT}$                      | RMS output current                                                                                                 | -                                                      | -        | 2.8    | A      |
| $f_{sw}$                       | Switching frequency                                                                                                | -                                                      | -        | 100    | KHz    |

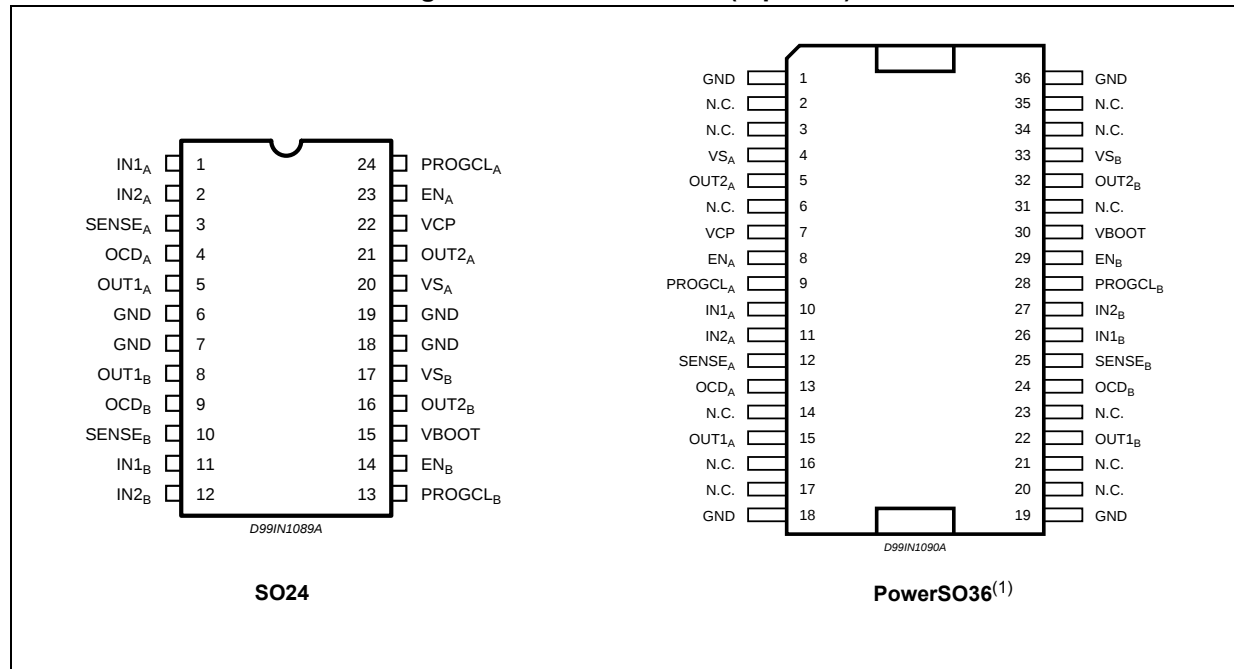
Table 3. Thermal data

| Symbol          | Description                                                | SO24 | PowerSO36 | Unit |
|-----------------|------------------------------------------------------------|------|-----------|------|
| $R_{th-j-pins}$ | Maximum thermal resistance junction pins                   | 14   | -         | °C/W |
| $R_{th-j-case}$ | Maximum thermal resistance junction case                   | -    | 1         | °C/W |
| $R_{th-j-amb1}$ | Maximum thermal resistance junction ambient <sup>(1)</sup> | 51   | -         | °C/W |
| $R_{th-j-amb1}$ | Maximum thermal resistance junction ambient <sup>(2)</sup> | -    | 35        | °C/W |
| $R_{th-j-amb1}$ | Maximum thermal resistance junction ambient <sup>(3)</sup> | -    | 15        | °C/W |
| $R_{th-j-amb2}$ | Maximum thermal resistance junction ambient <sup>(4)</sup> | 77   | 62        | °C/W |

1. Mounted on a multilayer FR4 PCB with a dissipating copper surface on the bottom side of 6 cm<sup>2</sup> (with a thickness of 35 µm).
2. Mounted on a multilayer FR4 PCB with a dissipating copper surface on the top side of 6 cm<sup>2</sup> (with a thickness of 35 µm).
3. Mounted on a multilayer FR4 PCB with a dissipating copper surface on the top side of 6 cm<sup>2</sup> (with a thickness of 35 µm), 16 via holes and a ground layer.
4. Mounted on a multilayer FR4 PCB without any heatsinking surface on the board.

### 3 Pin connections

Figure 2. Pin connections (top view)



1. The slug is internally connected to pins 1, 18, 19 and 36 (GND pins).

Table 4. Pin description

| Package      |               | Name               | Type              | Function                                                                                                                                                                             |
|--------------|---------------|--------------------|-------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SO24         | PowerSO36     |                    |                   |                                                                                                                                                                                      |
| Pin no.      | Pin no.       |                    |                   |                                                                                                                                                                                      |
| 1            | 10            | IN1 <sub>A</sub>   | Logic input       | Bridge A logic input 1.                                                                                                                                                              |
| 2            | 11            | IN2 <sub>A</sub>   | Logic input       | Bridge A logic input 2.                                                                                                                                                              |
| 3            | 12            | SENSE <sub>A</sub> | Power supply      | Bridge A source pin. This pin must be connected to power ground directly or through a sensing power resistor.                                                                        |
| 4            | 13            | OCD <sub>A</sub>   | Open drain output | Bridge A overcurrent detection and thermal protection pin. An internal open drain transistor pulls to GND when overcurrent on bridge A is detected or in case of thermal protection. |
| 5            | 15            | OUT1 <sub>A</sub>  | Power output      | Bridge A output 1.                                                                                                                                                                   |
| 6, 7, 18, 19 | 1, 18, 19, 36 | GND                | GND               | Signal ground terminals. In SO packages, these pins are also used for heat dissipation toward the PCB.                                                                               |
| 8            | 22            | OUT1 <sub>B</sub>  | Power output      | Bridge B output 1.                                                                                                                                                                   |

Table 4. Pin description (continued)

| Package |           | Name                | Type              | Function                                                                                                                                                                                                                                                    |
|---------|-----------|---------------------|-------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SO24    | PowerSO36 |                     |                   |                                                                                                                                                                                                                                                             |
| Pin no. | Pin no.   |                     |                   |                                                                                                                                                                                                                                                             |
| 9       | 24        | OCD <sub>B</sub>    | Open drain output | Bridge B overcurrent detection and thermal protection pin. An internal open drain transistor pulls to GND when overcurrent on bridge B is detected or in case of thermal protection.                                                                        |
| 10      | 25        | SENSE <sub>B</sub>  | Power supply      | Bridge B source pin. This pin must be connected to power ground directly or through a sensing power resistor.                                                                                                                                               |
| 11      | 26        | IN1 <sub>B</sub>    | Logic input       | Bridge B input 1                                                                                                                                                                                                                                            |
| 12      | 27        | IN2 <sub>B</sub>    | Logic input       | Bridge B input 2                                                                                                                                                                                                                                            |
| 13      | 28        | PROGCL <sub>B</sub> | R pin             | Bridge B overcurrent level programming. A resistor connected between this pin and ground sets the programmable current limiting value for the bridge B. By connecting this pin to ground the maximum current is set. This pin cannot be left non-connected. |
| 14      | 29        | EN <sub>B</sub>     | Logic input       | Bridge B Enable. LOW logic level switches OFF all power MOSFETs of Bridge B.<br>If not used, it has to be connected to +5 V.                                                                                                                                |
| 15      | 30        | VBOOT               | Supply voltage    | Bootstrap voltage needed for driving the upper power MOSFETs of both bridge A and bridge B.                                                                                                                                                                 |
| 16      | 32        | OUT2 <sub>B</sub>   | Power output      | Bridge B output 2.                                                                                                                                                                                                                                          |
| 17      | 33        | VS <sub>B</sub>     | Power supply      | Bridge B power supply voltage. It must be connected to the supply voltage together with pin VS <sub>A</sub> .                                                                                                                                               |
| 20      | 4         | VS <sub>A</sub>     | Power supply      | Bridge A power supply voltage. It must be connected to the supply voltage together with pin VS <sub>B</sub> .                                                                                                                                               |
| 21      | 5         | OUT2 <sub>A</sub>   | Power output      | Bridge A output 2.                                                                                                                                                                                                                                          |
| 22      | 7         | VCP                 | Output            | Charge pump oscillator output.                                                                                                                                                                                                                              |
| 23      | 8         | EN <sub>A</sub>     | Logic input       | Bridge A enable. LOW logic level switches OFF all power MOSFETs of bridge A.<br>If not used, it has to be connected to +5 V.                                                                                                                                |
| 24      | 9         | PROGCL <sub>A</sub> | R pin             | Bridge A overcurrent level programming. A resistor connected between this pin and ground sets the programmable current limiting value for the bridge A. By connecting this pin to ground the maximum current is set. This pin cannot be left non-connected. |

## 4 Electrical characteristics

**Table 5. Electrical characteristics ( $T_{amb} = 25\text{ °C}$ ,  $V_S = 48\text{ V}$ , unless otherwise specified)**

| Symbol                    | Parameter                                        | Test conditions                                                      | Min.  | Typ. | Max. | Unit |
|---------------------------|--------------------------------------------------|----------------------------------------------------------------------|-------|------|------|------|
| V <sub>Sth(ON)</sub>      | Turn-on threshold                                | -                                                                    | 6.6   | 7    | 7.4  | V    |
| V <sub>Sth(OFF)</sub>     | Turn-off threshold                               | -                                                                    | 5.6   | 6    | 6.4  | V    |
| I <sub>S</sub>            | Quiescent supply current                         | All bridges OFF;<br>T <sub>j</sub> = -25 °C to 125 °C <sup>(1)</sup> | -     | 5    | 10   | mA   |
| T <sub>j(OFF)</sub>       | Thermal shutdown temperature                     | -                                                                    | -     | 165  | -    | °C   |
| Output DMOS transistors   |                                                  |                                                                      |       |      |      |      |
| R <sub>DS(ON)</sub>       | High-side switch ON resistance                   | T <sub>j</sub> = 25 °C                                               | -     | 0.34 | 0.4  | Ω    |
|                           |                                                  | T <sub>j</sub> = 125 °C <sup>(1)</sup>                               | -     | 0.53 | 0.59 | Ω    |
|                           | Low-side switch ON resistance                    | T <sub>j</sub> = 25 °C                                               | -     | 0.28 | 0.34 | Ω    |
|                           |                                                  | T <sub>j</sub> = 125 °C <sup>(1)</sup>                               | -     | 0.47 | 0.53 | Ω    |
| I <sub>DSS</sub>          | Leakage current                                  | EN = low; OUT = V <sub>S</sub>                                       | -     | -    | 2    | mA   |
|                           |                                                  | EN = low; OUT = GND                                                  | -0.15 | -    | -    | mA   |
| Source drain diodes       |                                                  |                                                                      |       |      |      |      |
| V <sub>SD</sub>           | Forward ON voltage                               | I <sub>SD</sub> = 2.8 A, EN = low                                    | -     | 1.15 | 1.3  | V    |
| t <sub>rr</sub>           | Reverse recovery time                            | I <sub>f</sub> = 2.8 A                                               | -     | 300  | -    | ns   |
| t <sub>fr</sub>           | Forward recovery time                            | -                                                                    | -     | 200  | -    | ns   |
| Logic input               |                                                  |                                                                      |       |      |      |      |
| V <sub>IL</sub>           | Low level logic input voltage                    | -                                                                    | -0.3  | -    | 0.8  | V    |
| V <sub>IH</sub>           | High level logic input voltage                   | -                                                                    | 2     | -    | 7    | V    |
| I <sub>IL</sub>           | Low level logic input current                    | GND logic input voltage                                              | -10   | -    | -    | μA   |
| I <sub>IH</sub>           | High level logic input current                   | 7 V logic input voltage                                              | -     | -    | 10   | μA   |
| V <sub>th(ON)</sub>       | Turn-on input threshold                          | -                                                                    | -     | 1.8  | 2.0  | V    |
| V <sub>th(OFF)</sub>      | Turn-off input threshold                         | -                                                                    | 0.8   | 1.3  | -    | V    |
| V <sub>th(HYS)</sub>      | Input threshold hysteresis                       | -                                                                    | 0.25  | 0.5  | -    | V    |
| Switching characteristics |                                                  |                                                                      |       |      |      |      |
| t <sub>D(on)EN</sub>      | Enable to out turn ON delay time <sup>(2)</sup>  | I <sub>LOAD</sub> = 2.8 A, resistive load                            | 100   | 250  | 400  | ns   |
| t <sub>D(on)IN</sub>      | Input to out turn ON delay time                  | I <sub>LOAD</sub> = 2.8 A, resistive load<br>(deadtime included)     | -     | 1.6  | -    | μs   |
| t <sub>RISE</sub>         | Output rise time <sup>(2)</sup>                  | I <sub>LOAD</sub> = 2.8 A, resistive load                            | 40    | -    | 250  | ns   |
| t <sub>D(off)EN</sub>     | Enable to out turn OFF delay time <sup>(2)</sup> | I <sub>LOAD</sub> = 2.8 A, resistive load                            | 300   | 550  | 800  | ns   |
| t <sub>D(off)IN</sub>     | Input to out turn OFF delay time                 | I <sub>LOAD</sub> = 2.8 A, resistive load                            | -     | 600  | -    | ns   |
| t <sub>FALL</sub>         | Output fall time <sup>(2)</sup>                  | I <sub>LOAD</sub> = 2.8 A, resistive load                            | 40    | -    | 250  | ns   |

Table 5. Electrical characteristics ( $T_{amb} = 25\text{ °C}$ ,  $V_s = 48\text{ V}$ , unless otherwise specified) (continued)

| Symbol                       | Parameter                                    | Test conditions                                                      | Min. | Typ. | Max. | Unit          |
|------------------------------|----------------------------------------------|----------------------------------------------------------------------|------|------|------|---------------|
| $t_{dt}$                     | Deadtime protection                          | -                                                                    | 0.5  | 1    | -    | $\mu\text{s}$ |
| $f_{CP}$                     | Charge pump frequency                        | $-25\text{ °C} < T_j < 125\text{ °C}$                                | -    | 0.6  | 1    | MHz           |
| <b>Overcurrent detection</b> |                                              |                                                                      |      |      |      |               |
| $I_{s\text{ over}}$          | Input supply overcurrent detection threshold | $-25\text{ °C} < T_j < 125\text{ °C}$ ; $R_{CL} = 39\text{ k}\Omega$ | -10% | 0.57 | +10% | A             |
|                              |                                              | $-25\text{ °C} < T_j < 125\text{ °C}$ ; $R_{CL} = 5\text{ k}\Omega$  | -10% | 4.42 | +10% | A             |
|                              |                                              | $-25\text{ °C} < T_j < 125\text{ °C}$ ; $R_{CL} = \text{GND}$        | -30% | 5.6  | +30% | A             |
| $R_{OPDR}$                   | Open drain ON resistance                     | $I = 4\text{ mA}$                                                    | -    | 40   | 60   | $\Omega$      |
| $t_{OCD(ON)}$                | OCD turn-on delay time <sup>(3)</sup>        | $I = 4\text{ mA}$ ; $C_{EN} < 100\text{ pF}$                         | -    | 200  | -    | ns            |
| $t_{OCD(OFF)}$               | OCD turn-off delay time <sup>(3)</sup>       | $I = 4\text{ mA}$ ; $C_{EN} < 100\text{ pF}$                         | -    | 100  | -    | ns            |

1. Tested at  $25\text{ °C}$  in a restricted range and guaranteed by characterization.

2. See [Figure 3: Switching characteristic definition](#).

3. See [Figure 4: Overcurrent detection timing definition](#).

Figure 3. Switching characteristic definition

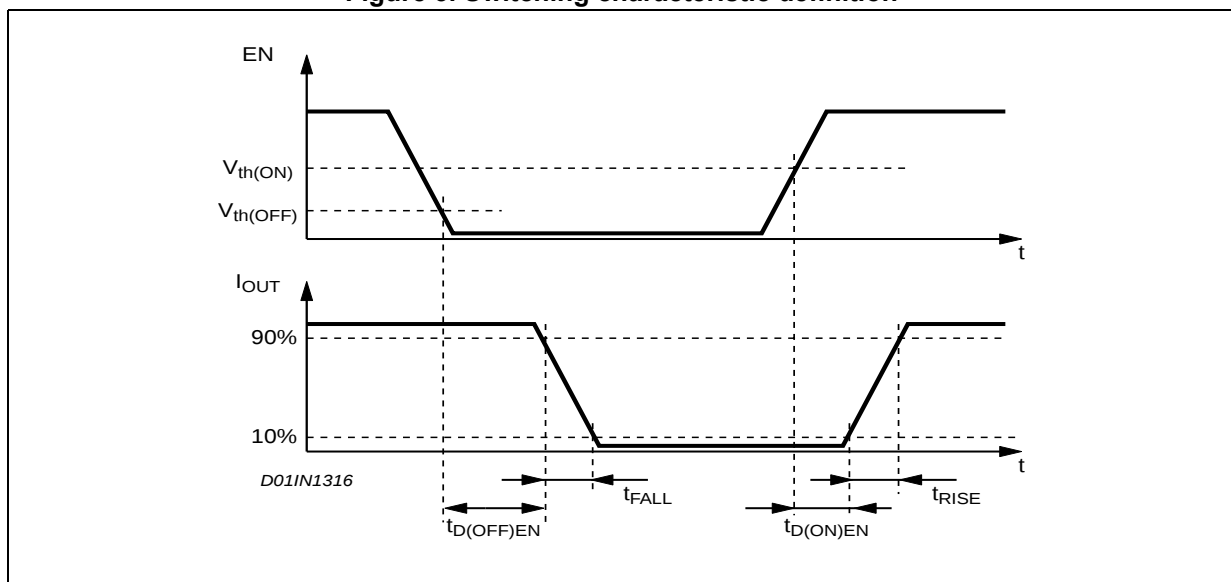
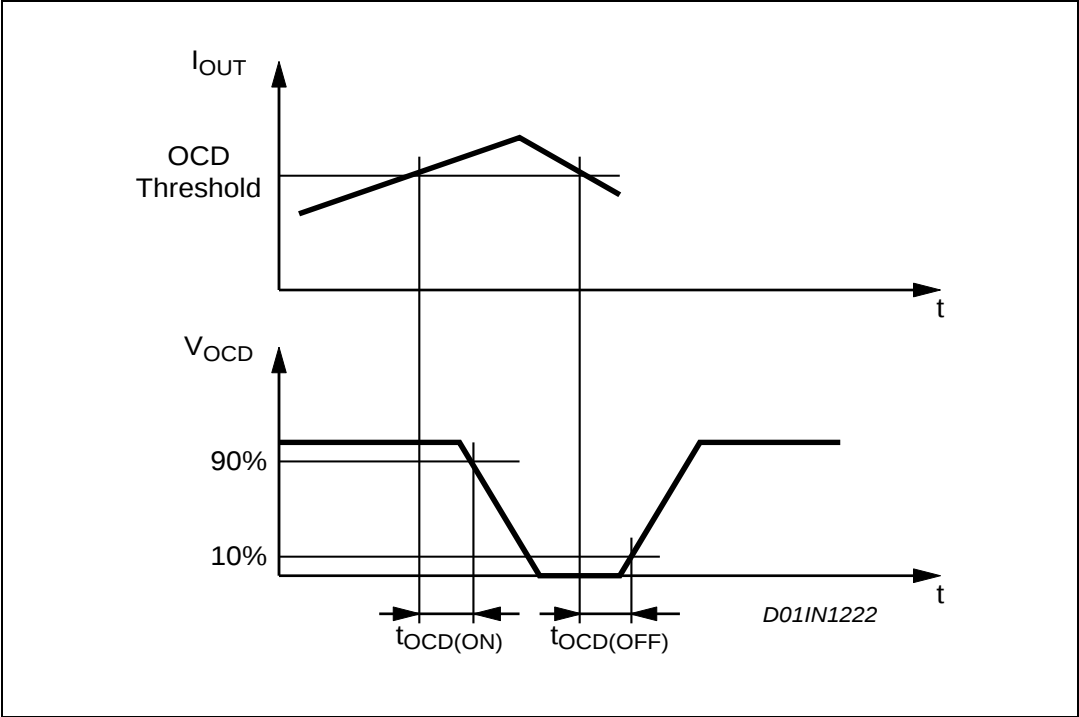


Figure 4. Overcurrent detection timing definition



## 5 Circuit description

### 5.1 Power stages and charge pump

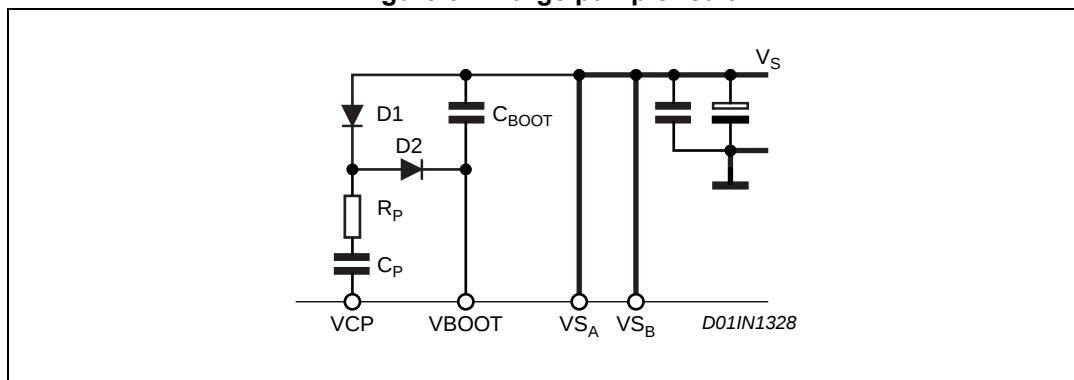
The L6206 device integrates two independent power MOS full bridges. Each power MOS has an  $R_{ds(ON)} = 0.3 \Omega$  (typical value at 25 °C), with intrinsic fast freewheeling diode. Cross conduction protection is achieved using a deadtime ( $t_d = 1 \mu s$  typical) between the switch off and switch on of two power MOS in one leg of a bridge.

Using N-channel power MOS for the upper transistors in the bridge requires a gate drive voltage above the power supply voltage. The bootstrapped ( $V_{BOOT}$ ) supply is obtained through an internal oscillator and few external components to realize a charge pump circuit as shown in [Figure 5](#). The oscillator output (VCP) is a square wave at 600 kHz (typical) with 10 V amplitude. Recommended values/part numbers for the charge pump circuit are shown in [Table 6](#).

**Table 6. Charge pump external components values**

| Component  | Value        |
|------------|--------------|
| $C_{BOOT}$ | 220 nF       |
| $C_P$      | 10 nF        |
| $R_P$      | 100 $\Omega$ |
| D1         | 1N4148       |
| D2         | 1N4148       |

**Figure 5. Charge pump circuit**

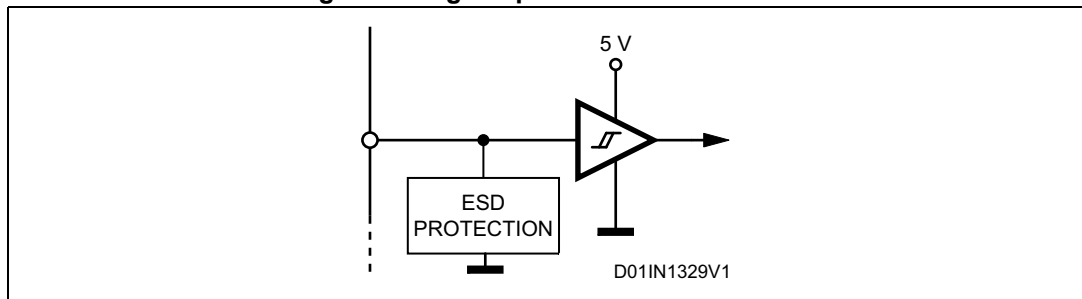


## 5.2 Logic inputs

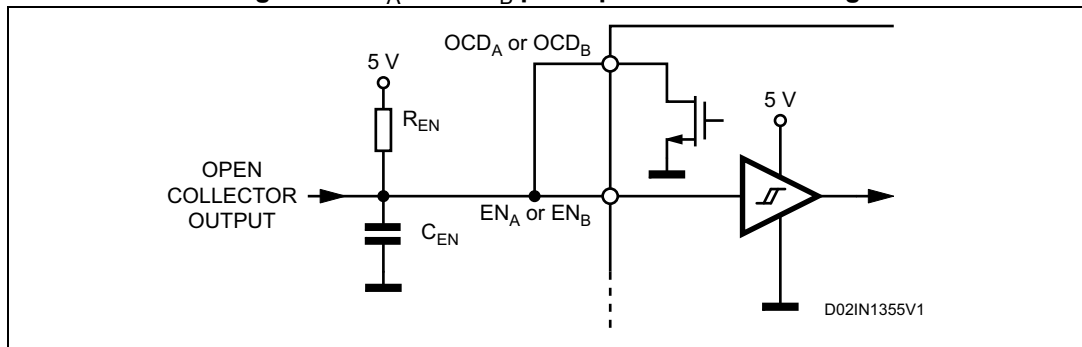
Pins IN1<sub>A</sub>, IN2<sub>A</sub>, IN1<sub>B</sub>, IN2<sub>B</sub>, EN<sub>A</sub> and EN<sub>B</sub> are TTL/CMOS compatible logic inputs. The internal structure is shown in [Figure 6](#). Typical value for turn-on and turn-off thresholds are respectively  $V_{th(ON)} = 1.8\text{ V}$  and  $V_{th(OFF)} = 1.3\text{ V}$ .

Pins EN<sub>A</sub> and EN<sub>B</sub> are commonly used to implement overcurrent and thermal protection by connecting them respectively to the outputs OCD<sub>A</sub> and OCD<sub>B</sub>, which are open drain outputs. If that type of connection is chosen, some care needs to be taken in driving these pins. Two configurations are shown in [Figure 7](#) and [Figure 8](#). If driven by an open drain (collector) structure, a pull-up resistor  $R_{EN}$  and a capacitor  $C_{EN}$  are connected as shown in [Figure 7](#). If the driver is a standard push-pull structure, the resistor  $R_{EN}$  and the capacitor  $C_{EN}$  are connected as shown in [Figure 8](#). The resistor  $R_{EN}$  should be chosen in the range from 2.2 k $\Omega$  to 180 k $\Omega$ . Recommended values for  $R_{EN}$  and  $C_{EN}$  are respectively 100 k $\Omega$  and 5.6 nF. More information on selecting the values is found in [Section 5.3: Non-dissipative overcurrent detection and protection](#).

**Figure 6. Logic inputs internal structure**



**Figure 7. EN<sub>A</sub> and EN<sub>B</sub> pins open collector driving**



**Figure 8. EN<sub>A</sub> and EN<sub>B</sub> pins push-pull driving**

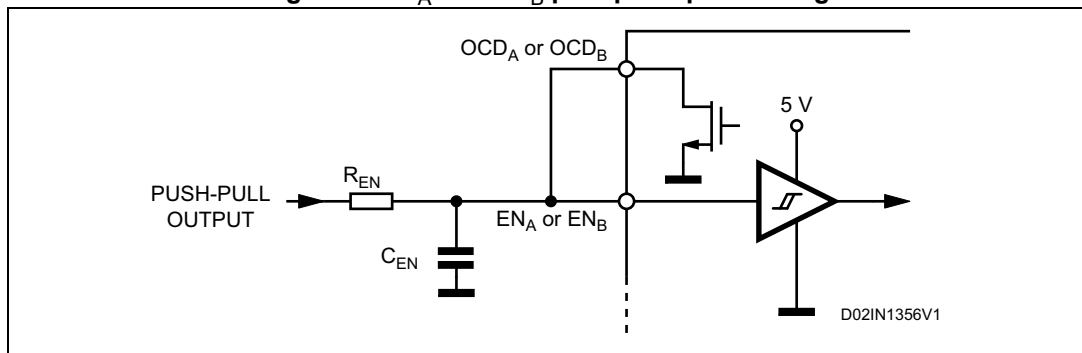


Table 7. Truth table

| Inputs |                  |                  | Outputs               |                       |
|--------|------------------|------------------|-----------------------|-----------------------|
| EN     | IN1              | IN2              | OUT1                  | OUT2                  |
| L      | X <sup>(1)</sup> | X <sup>(1)</sup> | High Z <sup>(2)</sup> | High Z <sup>(2)</sup> |
| H      | L                | L                | GND                   | GND                   |
| H      | H                | L                | Vs                    | GND                   |
| H      | L                | H                | GND                   | Vs                    |
| H      | H                | H                | Vs                    | Vs                    |

1. X = don't care.

2. High Z = high impedance output.

### 5.3 Non-dissipative overcurrent detection and protection

In addition to the PWM current control, an overcurrent detection circuit (OCD) is integrated. This circuit can be used to provide protection against a short-circuit to ground or between two phases of the bridge as well as a roughly regulation of the load current. With this internal overcurrent detection, the external current sense resistor normally used and its associated power dissipation are eliminated. [Figure 9](#) shows a simplified schematic of the overcurrent detection circuit for the bridge A. Bridge B is provided of an analogous circuit.

To implement the overcurrent detection, a sensing element that delivers a small but precise fraction of the output current is implemented with each high-side power MOS. Since this current is a small fraction of the output current there is very little additional power dissipation. This current is compared with an internal reference current  $I_{REF}$ . When the output current reaches the detection threshold  $I_{SOVER}$  the OCD comparator signals a fault condition. When a fault condition is detected, an internal open drain MOS with a pull down capability of 4 mA connected to OCD pin is turned on. [Figure 10](#) shows the OCD operation.

This signal can be used to regulate the output current simply by connecting the OCD pin to EN pin and adding an external R-C as shown in [Figure 9](#). The off time before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs.

$I_{REF}$  and, therefore, the output current detection threshold are selectable by  $R_{CL}$  value, following the equations:

$$-I_{SOVER} = 5.6 \text{ A} \pm 30\% \quad \text{at } -25^\circ\text{C} < T_j < 125^\circ\text{C} \quad \text{if } R_{CL} = 0 \Omega \text{ (PROGCL connected to GND)}$$

$$-I_{SOVER} = \frac{22100}{R_{CL}} \pm 10\% \quad \text{at } -25^\circ\text{C} < T_j < 125^\circ\text{C} \quad \text{if } 5 \text{ k}\Omega < R_{CL} < 40 \text{ k}\Omega$$

[Figure 11](#) shows the output current protection threshold versus  $R_{CL}$  value in the range 5 k $\Omega$  to 40 k $\Omega$ .

The disable time  $t_{DISABLE}$  before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs. It is affected whether by  $C_{EN}$  and  $R_{EN}$  values and its magnitude is reported in [Figure 12](#). The delay time  $t_{DELAY}$  before turning off the bridge when an overcurrent has been detected depends only by  $C_{EN}$  value. Its magnitude is reported in [Figure 13](#).

$C_{EN}$  is also used for providing immunity to pin EN against fast transient noises. Therefore the value of  $C_{EN}$  should be chosen as big as possible according to the maximum tolerable delay time and the  $R_{EN}$  value should be chosen according to the desired disable time.

The resistor  $R_{EN}$  should be chosen in the range from 2.2 K $\Omega$  to 180 K $\Omega$ . Recommended values for  $R_{EN}$  and  $C_{EN}$  are respectively 100 K $\Omega$  and 5.6 nF that allow obtaining 200  $\mu$ s disable time.

**Figure 9. Overcurrent protection simplified schematic**

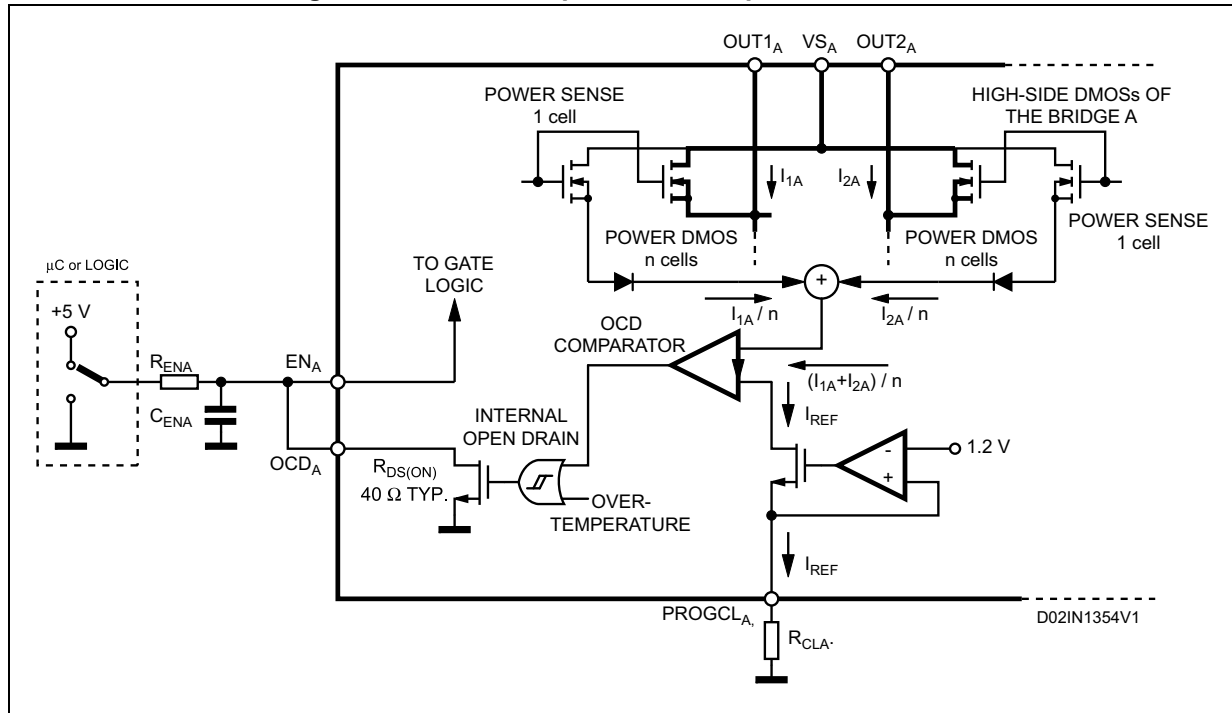


Figure 10. Overcurrent protection waveforms

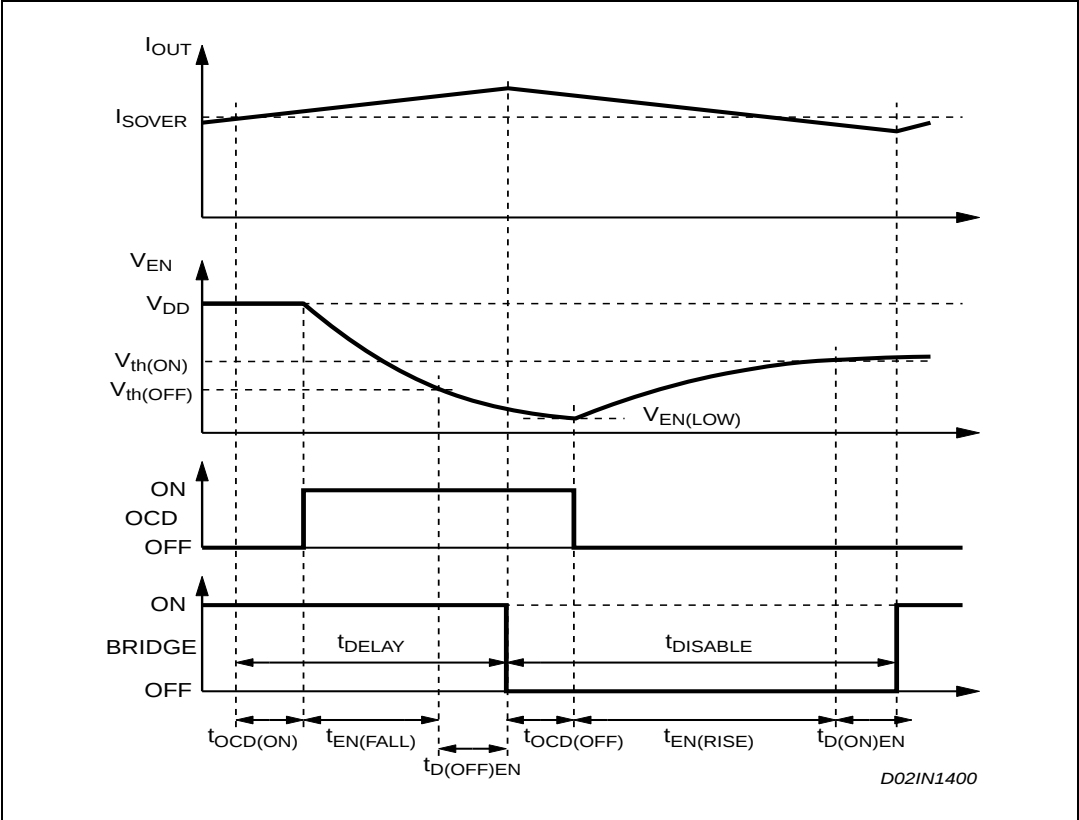


Figure 11. Output current protection threshold versus  $R_{CL}$  value

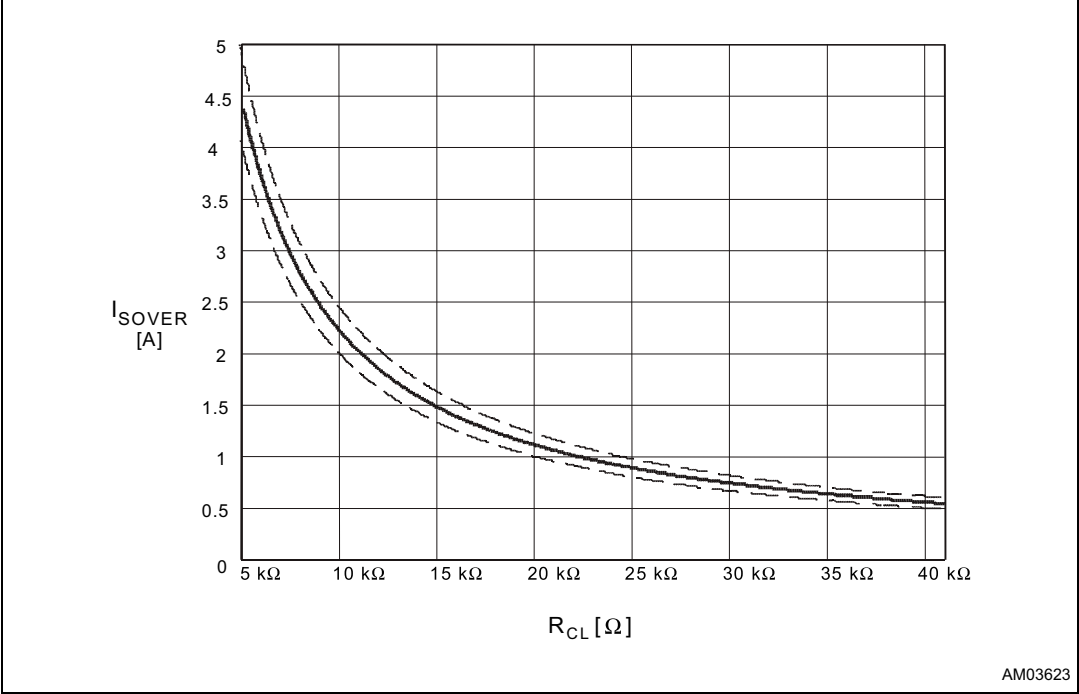
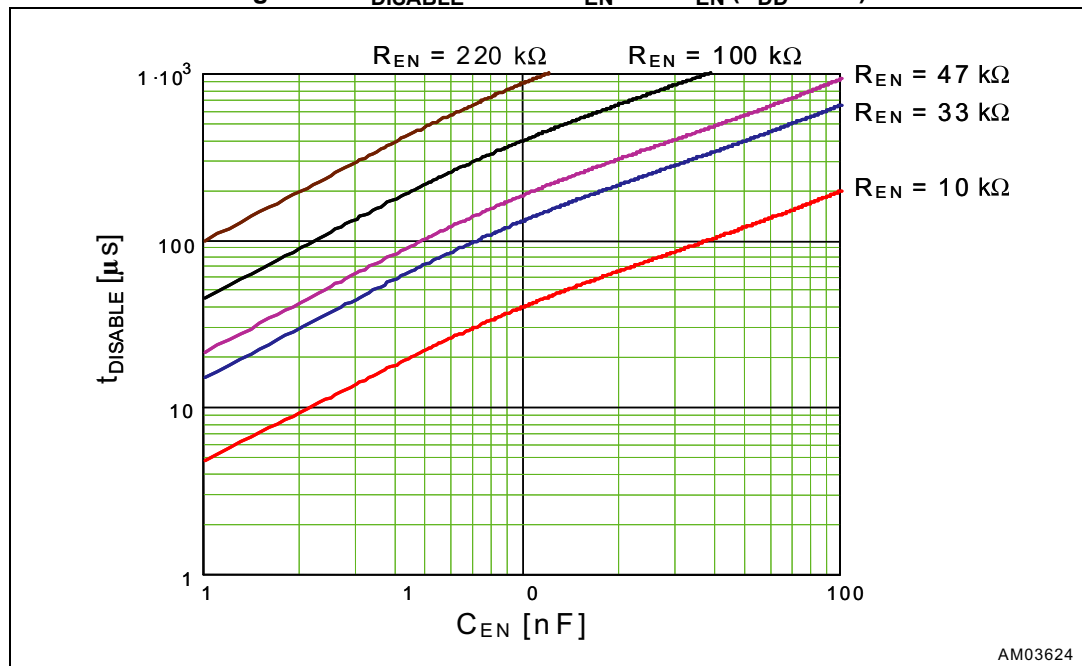
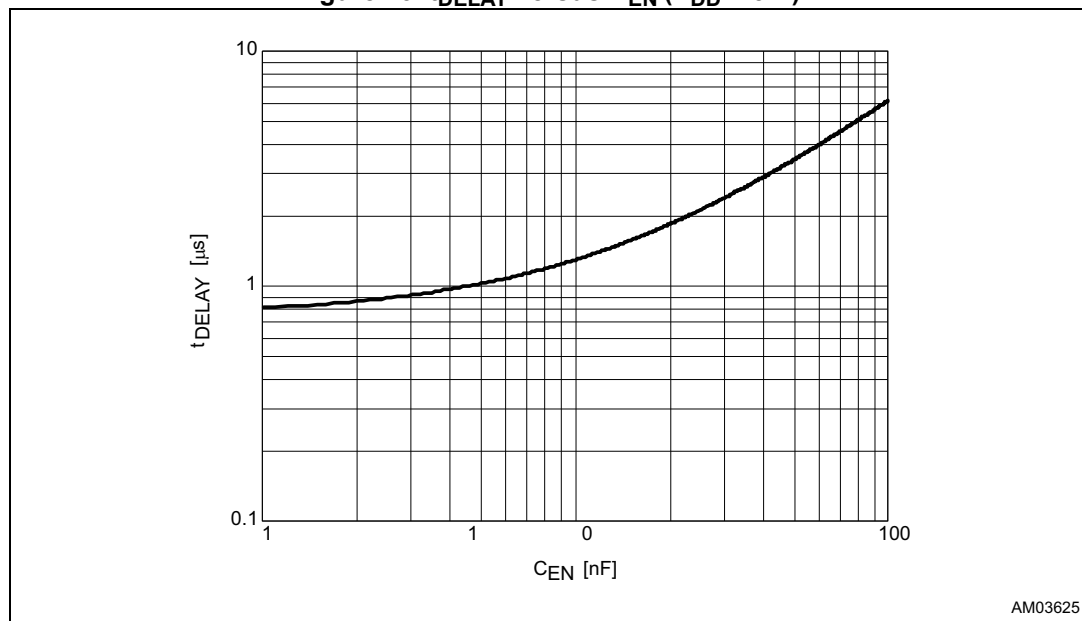


Figure 12.  $t_{\text{DISABLE}}$  versus  $C_{\text{EN}}$  and  $R_{\text{EN}}$  ( $V_{\text{DD}} = 5 \text{ V}$ )Figure 13.  $t_{\text{DELAY}}$  versus  $C_{\text{EN}}$  ( $V_{\text{DD}} = 5 \text{ V}$ )

## 5.4 Thermal protection

In addition to the overcurrent detection, the L6206 device integrates a thermal protection for preventing the device destruction in case of junction overtemperature. It works sensing the die temperature by means of a sensible element integrated in the die. The device switches-off when the junction temperature reaches 165 °C (typ. value) with 15 °C hysteresis (typ. value).

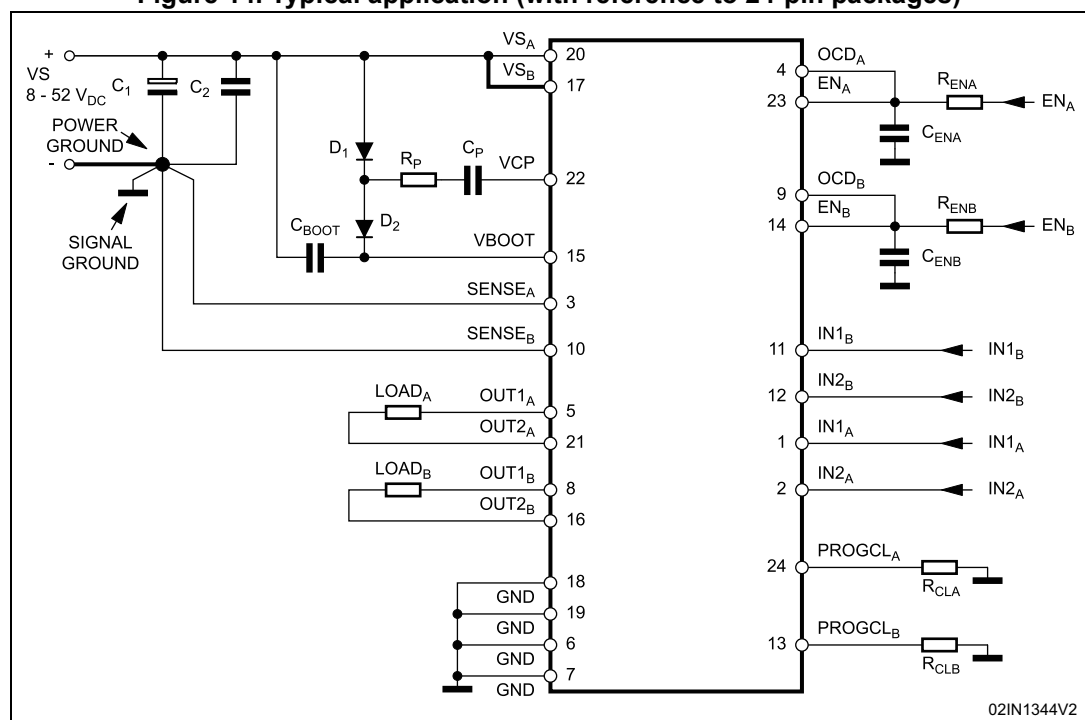
## 6 Application information

A typical application using the L6206 device is shown in [Figure 14](#). Typical component values for the application are shown in [Table 8](#). A high quality ceramic capacitor in the range of 100 to 200 nF should be placed between the power pins ( $VS_A$  and  $VS_B$ ) and ground near the L6206 device to improve the high frequency filtering on the power supply and reduce high frequency transients generated by the switching. The capacitors connected from the  $EN_A/OCD_A$  and  $EN_B/OCD_B$  nodes to ground set the shutdown time for the bridge A and bridge B respectively when an overcurrent is detected (see [Section 5.3: Non-dissipative overcurrent detection and protection on page 13](#)). The two current sources ( $SENSE_A$  and  $SENSE_B$ ) should be connected to power ground with a trace length as short as possible in the layout. To increase noise immunity, unused logic pins are best connected to 5 V (high logic level) or GND (low logic level) (see [Table 4: Pin description on page 6](#)). It is recommended to keep power ground and signal ground separated on the PCB.

**Table 8. Component values for typical application**

| Component  | Value       | Component | Value         |
|------------|-------------|-----------|---------------|
| $C_1$      | 100 $\mu$ F | $D_1$     | 1N4148        |
| $C_2$      | 100 nF      | $D_2$     | 1N4148        |
| $C_{BOOT}$ | 220 nF      | $R_{CLA}$ | 5 $K\Omega$   |
| $C_P$      | 10 nF       | $R_{CLB}$ | 5 $K\Omega$   |
| $C_{ENA}$  | 5.6 nF      | $R_{ENA}$ | 100 $k\Omega$ |
| $C_{ENB}$  | 5.6 nF      | $R_{ENB}$ | 100 $k\Omega$ |

**Figure 14. Typical application (with reference to 24-pin packages)**



## 6.1 Paralleled operation

The outputs of the L6206 device can be paralleled to increase the output current capability or reduce the power dissipation in the device at a given current level. It must be noted, however, that the internal wire bond connections from the die to the power or sense pins of the package must carry current in both of the associated half-bridges. When the two halves of one full bridge (for example OUT1<sub>A</sub> and OUT2<sub>A</sub>) are connected in parallel, the peak current rating is not increased since the total current must still flow through one bond wire on the power supply or sense pin. In addition the overcurrent detection senses the sum of the current in the upper devices of each bridge (A or B) so connecting the two halves of one bridge in parallel does not increase the overcurrent detection threshold.

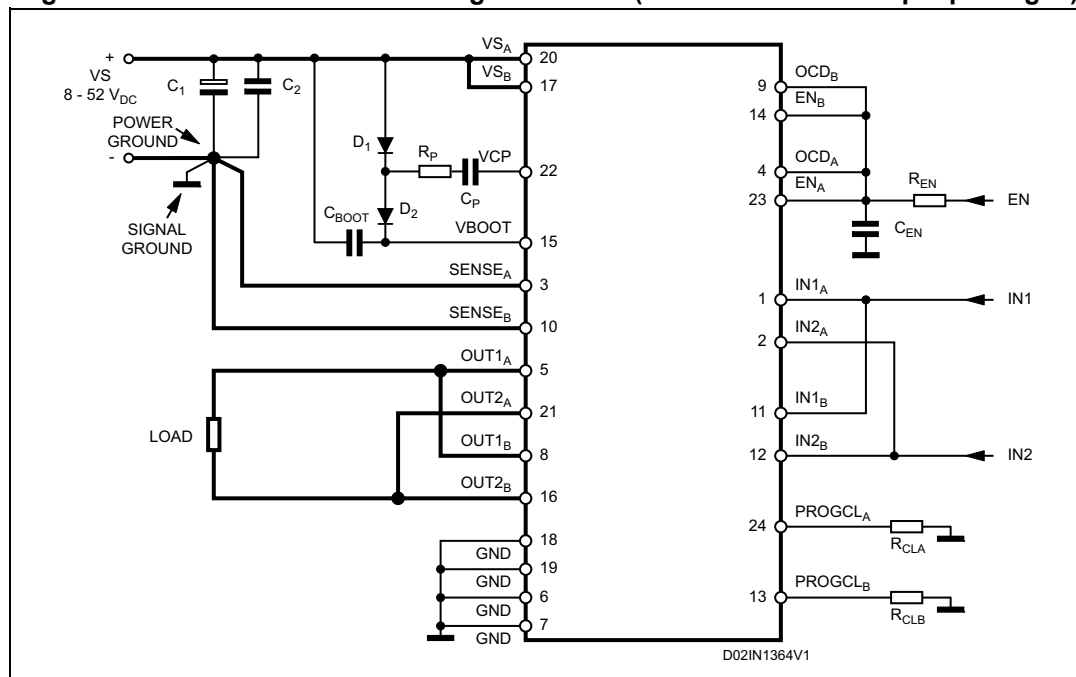
For most applications the recommended configuration is half-bridge 1 of bridge A paralleled with the half-bridge 1 of the bridge B, and the same for the half-bridges 2 as shown in [Figure 15](#). The current in the two devices connected in parallel will share very well since the  $R_{DS(ON)}$  of the devices on the same die is well matched.

When connected in this configuration the overcurrent detection circuit, which senses the current in each bridge (A and B), will sense the current in upper devices connected in parallel independently and the sense circuit with the lowest threshold will trip first. With the enables connected in parallel, the first detection of an overcurrent in either upper DMOS device will turn off both bridges. Assuming that the two DMOS devices share the current equally, the resulting overcurrent detection threshold will be twice the minimum threshold set by the resistors  $R_{CLA}$  or  $R_{CLB}$  in [Figure 15](#). It is recommended to use  $R_{CLA} = R_{CLB}$ .

In this configuration the resulting bridge has the following characteristics:

- Equivalent device: full bridge
- $R_{DS(ON)}$  0.15  $\Omega$  typ. value at  $T_J = 25\text{ }^{\circ}\text{C}$
- 5.6 A max. RMS load current
- 11.2 A max. OCD threshold

**Figure 15. Parallel connection for higher current (with reference to 24-pin packages)**



To operate the device in parallel and maintain a lower overcurrent threshold, half-bridge 1 and the half-bridge 2 of the bridge A can be connected in parallel and the same done for the bridge B as shown in [Figure 16](#). In this configuration, the peak current for each half-bridge is still limited by the bond wires for the supply and sense pins so the dissipation in the device will be reduced, but the peak current rating is not increased.

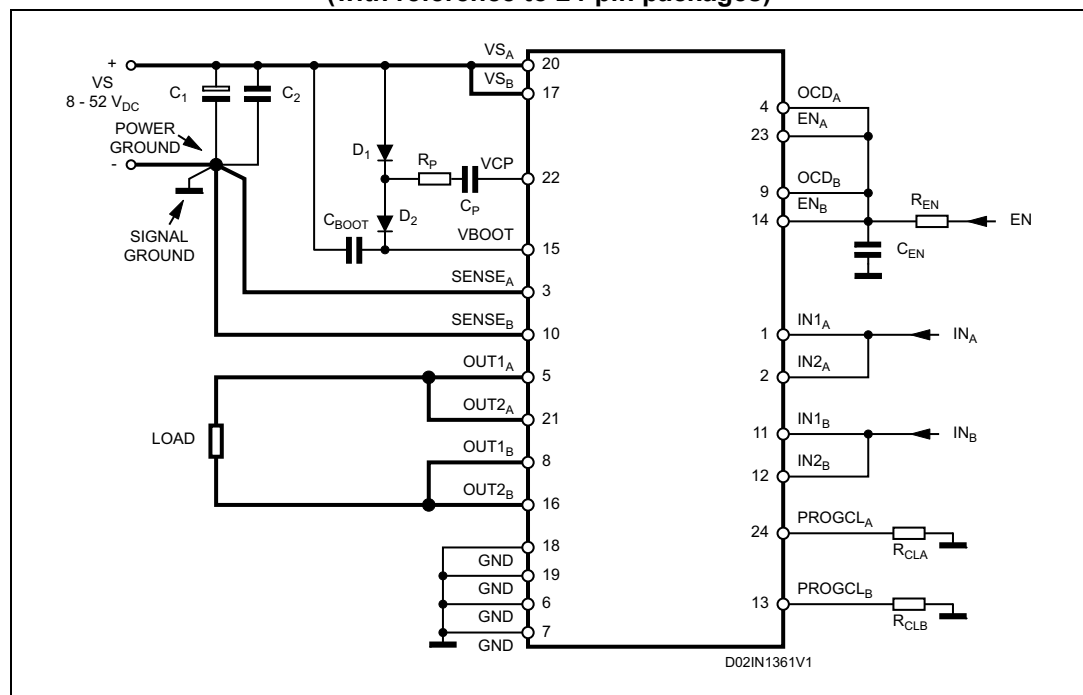
When connected in this configuration the overcurrent detection circuit, senses the sum of the current in upper devices connected in parallel. With the enables connected in parallel, an overcurrent will turn off both bridges. Since the circuit senses the total current in the upper devices, the overcurrent threshold is equal to the threshold set the resistor  $R_{CLA}$  or  $R_{CLB}$  in [Figure 16](#).  $R_{CLA}$  sets the threshold when outputs  $OUT1_A$  and  $OUT2_A$  are high and resistor  $R_{CLB}$  sets the threshold when outputs  $OUT1_B$  and  $OUT2_B$  are high.

It is recommended to use  $R_{CLA} = R_{CLB}$ .

In this configuration, the resulting bridge has the following characteristics:

- Equivalent device: full bridge
- $R_{DS(ON)}$  0.15  $\Omega$  typ. value at  $T_J = 25^\circ\text{C}$
- 2.8 A max. RMS load current
- 5.6 A max. OCD threshold

**Figure 16. Parallel connection with lower overcurrent threshold  
(with reference to 24-pin packages)**

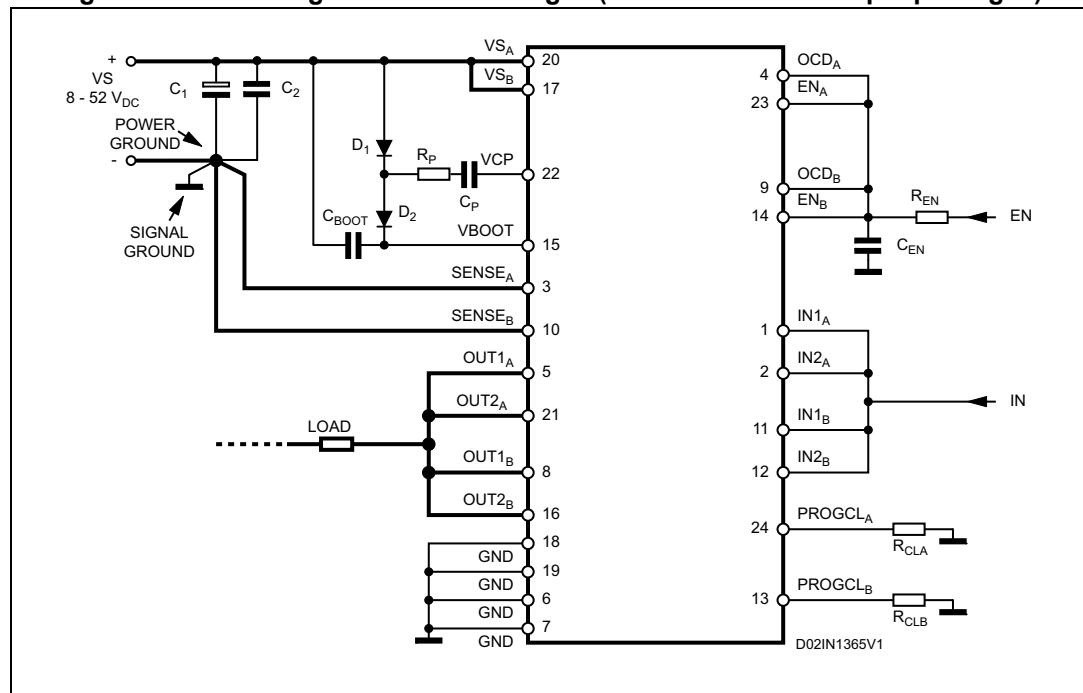


It is also possible to parallel the four half-bridges to obtain a simple half-bridge as shown in [Figure 17](#). In this configuration the overcurrent threshold is equal to twice the minimum threshold set by the resistors  $R_{CLA}$  or  $R_{CLB}$  in [Figure 17](#). It is recommended to use  $R_{CLA} = R_{CLB}$ .

The resulting half-bridge has the following characteristics:

- Equivalent device: half-bridge
- $R_{DS(ON)}$  0.075.Ω typ. value at  $T_J = 25\text{ }^{\circ}\text{C}$
- 5.6 A max. RMS load current
- 11.2 A max. OCD threshold

**Figure 17. Paralleling the four half-bridges (with reference to 24-pin packages)**



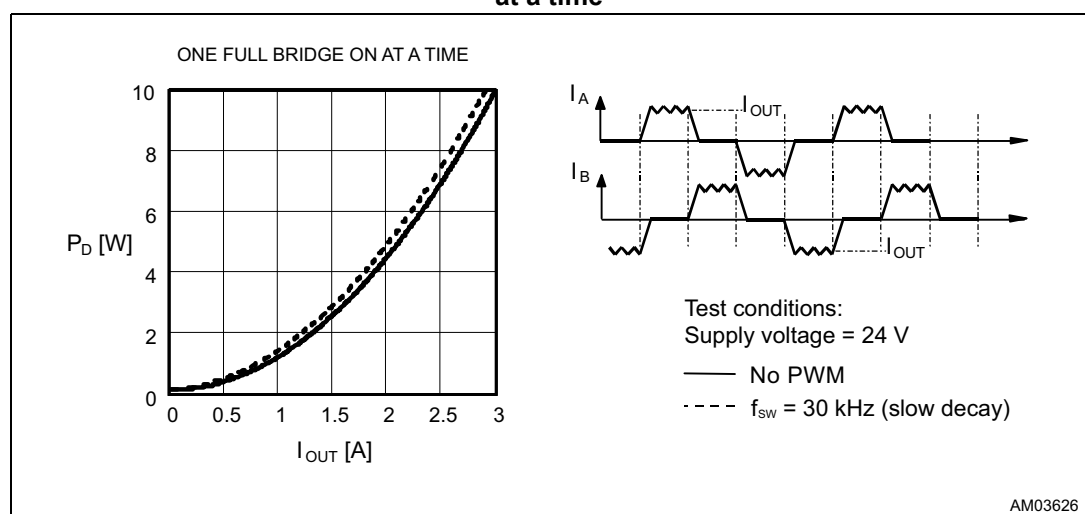
## 6.2 Output current capability and IC power dissipation

In [Figure 18](#) and [Figure 19](#) are shown the approximate relation between the output current and the IC power dissipation using PWM current control driving two loads, for two different driving types:

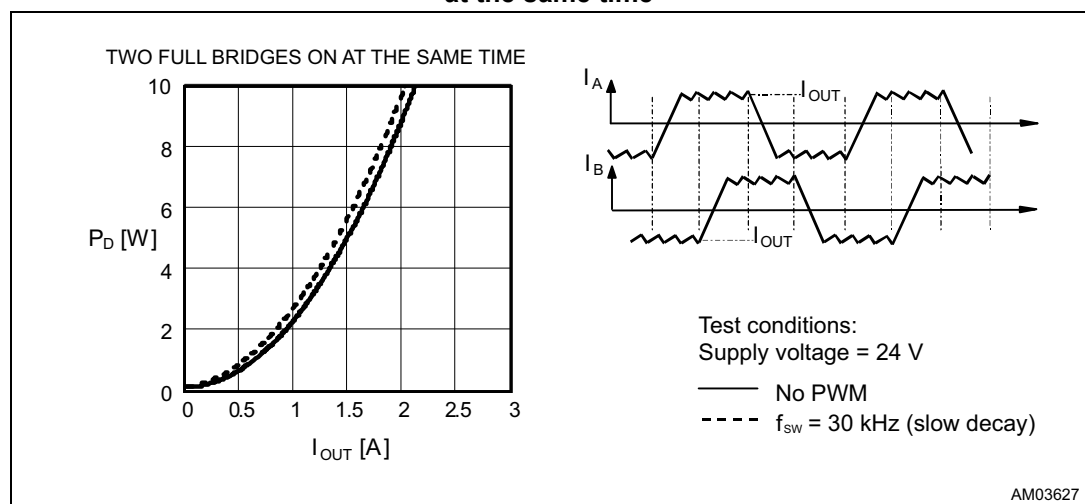
- One full bridge ON at a time ([Figure 18](#)) in which only one load at a time is energized.
- Two full bridges ON at the same time ([Figure 19](#)) in which two loads at the same time are energized.

For a given output current and driving type the power dissipated by the IC can be easily evaluated, in order to establish which package should be used and how large must be the on-board copper dissipating area to guarantee a safe operating junction temperature (125 °C maximum).

**Figure 18. IC power dissipation versus output current with one full bridge ON at a time**



**Figure 19. IC power dissipation versus output current with two full bridges ON at the same time**

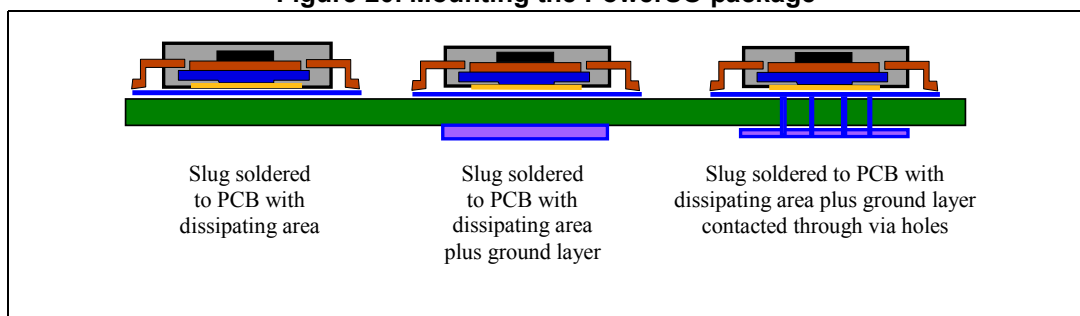


## 6.3 Thermal management

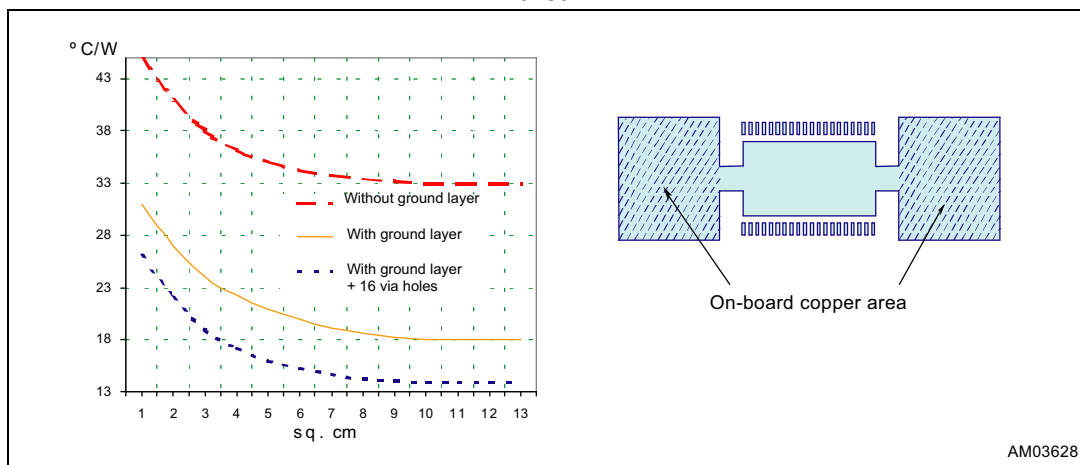
In most applications the power dissipation in the IC is the main factor that sets the maximum current that can be delivered by the device in a safe operating condition. Therefore, it has to be taken into account very carefully. Besides the available space on the PCB, the right package should be chosen considering the power dissipation. Heatsinking can be achieved using copper on the PCB with proper area and thickness. [Figure 21](#) and [22](#) show the junction to ambient thermal resistance values for the PowerSO36 and SO24 packages.

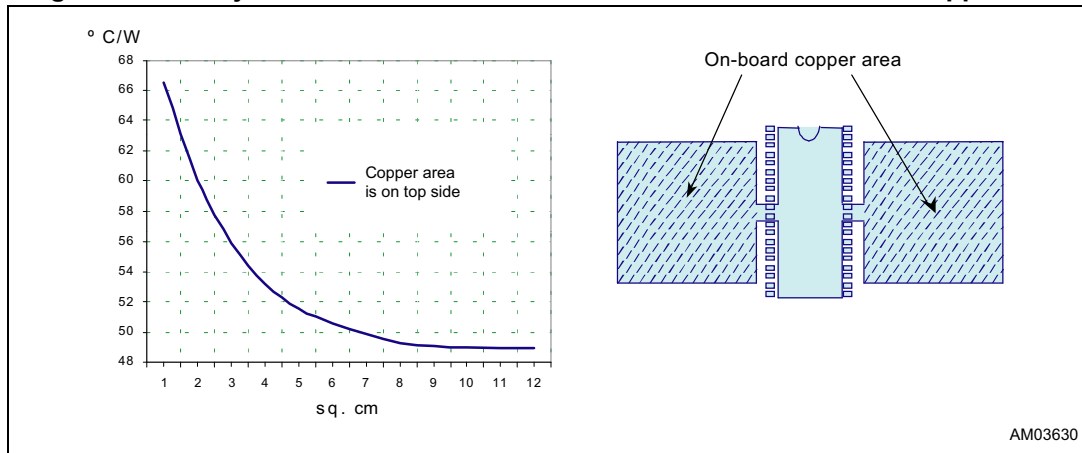
For instance, using a PowerSO package with a copper slug soldered on a 1.5 mm copper thickness FR4 board with a 6 cm<sup>2</sup> dissipating footprint (copper thickness of 35 µm), the  $R_{th\ j-amb}$  is about 35 °C/W. [Figure 20](#) shows mounting methods for this package. Using a multilayer board with vias to a ground plane, thermal impedance can be reduced down to 15 °C/W.

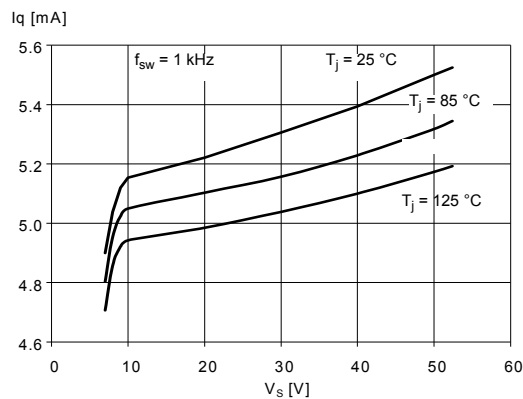
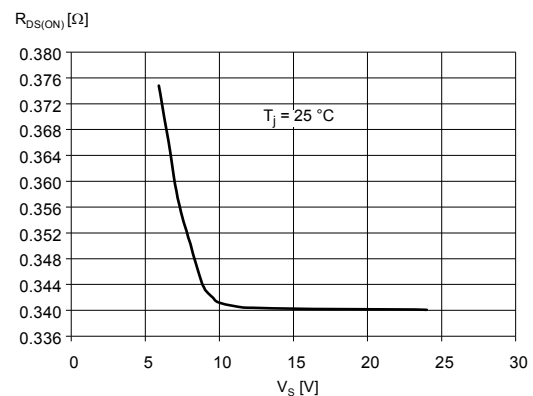
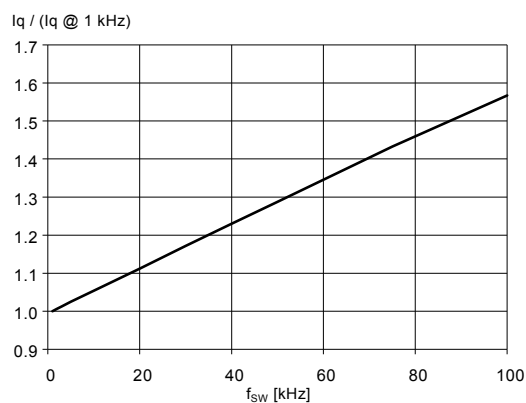
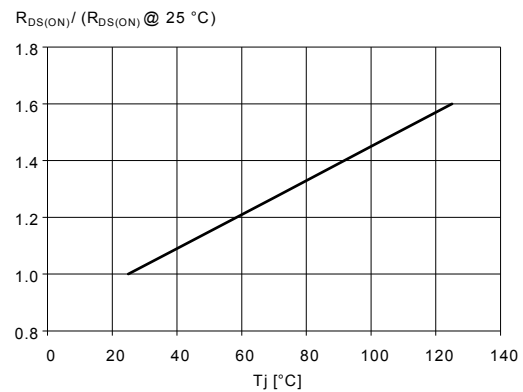
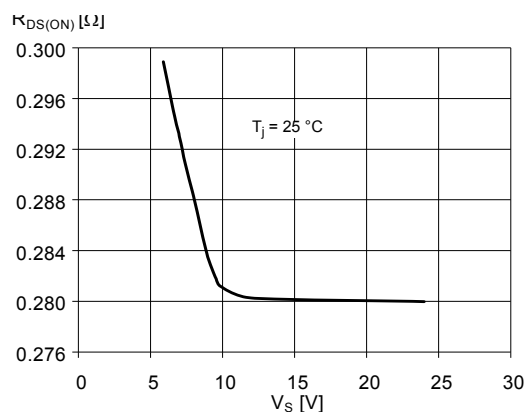
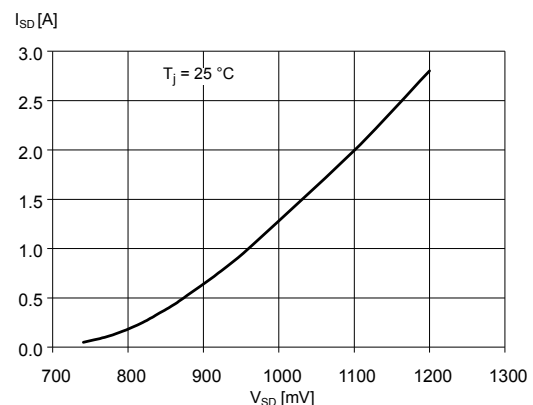
**Figure 20. Mounting the PowerSO package**



**Figure 21. PowerSO36 junction ambient thermal resistance versus on-board copper area**



**Figure 22. SO24 junction ambient thermal resistance versus on-board copper area**

**Figure 23. Typical quiescent current vs. supply voltage****Figure 24. Typical high-side  $R_{DS(ON)}$  vs. supply voltage****Figure 25. Normalized typical quiescent current vs. switching frequency****Figure 26. Normalized  $R_{DS(ON)}$  vs. junction temperature (typical value)****Figure 27. Typical low-side  $R_{DS(ON)}$  vs. supply voltage****Figure 28. Typical drain-source diode forward ON characteristic**

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 7.1 PowerSO36 package information

Figure 29. PowerSO36 package outline

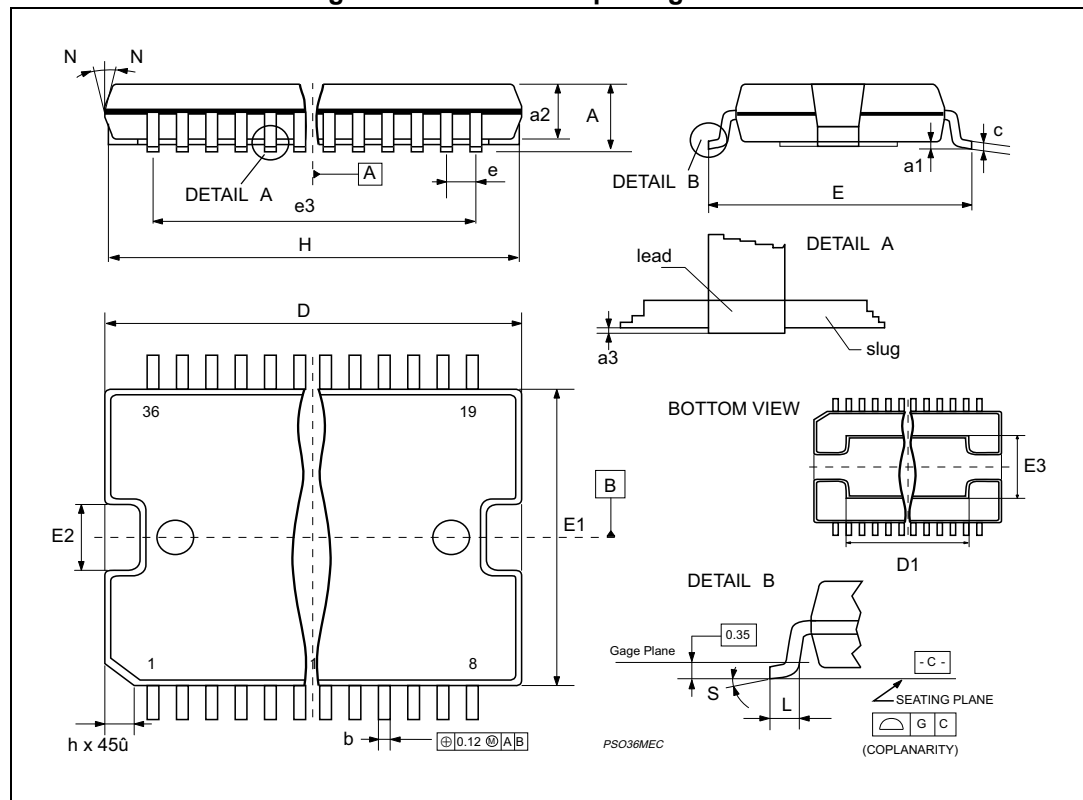


Table 9. PowerSO36 package mechanical data

| Symbol            | Dimensions (mm) |       |       | Dimensions (inch) |        |       |
|-------------------|-----------------|-------|-------|-------------------|--------|-------|
|                   | Min.            | Typ.  | Max.  | Min.              | Typ.   | Max.  |
| A                 | -               | -     | 3.60  | -                 | -      | 0.141 |
| a1                | 0.10            | -     | 0.30  | 0.004             | -      | 0.012 |
| a2                | -               | -     | 3.30  | -                 | -      | 0.130 |
| a3                | 0               | -     | 0.10  | 0                 | -      | 0.004 |
| b                 | 0.22            | -     | 0.38  | 0.008             | -      | 0.015 |
| c                 | 0.23            | -     | 0.32  | 0.009             | -      | 0.012 |
| D <sup>(1)</sup>  | 15.80           | -     | 16.00 | 0.622             | -      | 0.630 |
| D1                | 9.40            | -     | 9.80  | 0.370             | -      | 0.385 |
| E                 | 13.90           | -     | 14.50 | 0.547             | -      | 0.570 |
| e                 | -               | 0.65  | -     | -                 | 0.0256 | -     |
| e3                | -               | 11.05 | -     | -                 | 0.435  | -     |
| E1 <sup>(1)</sup> | 10.90           | -     | 11.10 | 0.429             | -      | 0.437 |
| E2                | -               | -     | 2.90  | -                 | -      | 0.114 |
| E3                | 5.80            | -     | 6.20  | 0.228             | -      | 0.244 |
| E4                | 2.90            | -     | 3.20  | 0.114             | -      | 0.126 |
| G                 | 0               | -     | 0.10  | 0                 | -      | 0.004 |
| H                 | 15.50           | -     | 15.90 | 0.610             | -      | 0.626 |
| h                 | -               | -     | 1.10  | -                 | -      | 0.043 |
| L                 | 0.80            | -     | 1.10  | 0.031             | -      | 0.043 |
| N                 | 10° (max.)      |       |       |                   |        |       |
| S                 | 8° (max.)       |       |       |                   |        |       |

1. "D" and "E1" do not include mold flash or protrusions.

- Mold flash or protrusions shall not exceed 0.15 mm (0.006 inch).

- Critical dimensions are "a3", "E" and "G".

## 7.2 SO24 package information

Figure 30. SO24 package outline

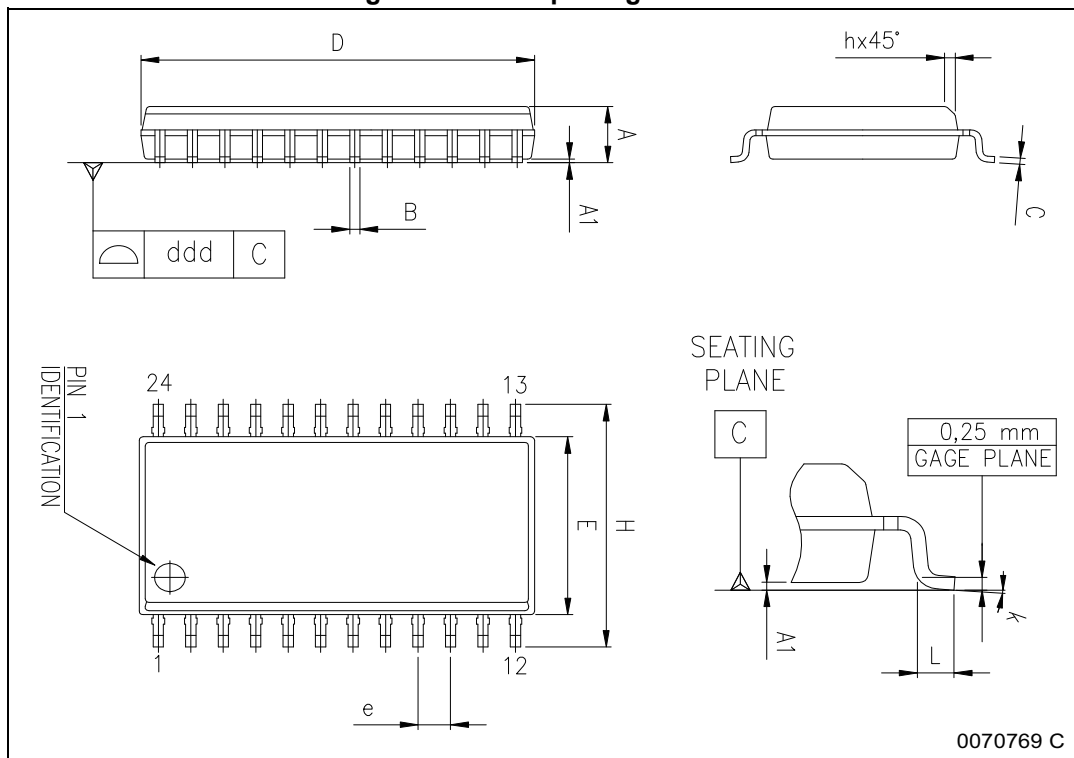


Table 10. SO24 package mechanical data

| Symbol           | Dimensions (mm)      |      |       | Dimensions (inch) |       |       |
|------------------|----------------------|------|-------|-------------------|-------|-------|
|                  | Min.                 | Typ. | Max.  | Min.              | Typ.  | Max.  |
| A                | 2.35                 | -    | 2.65  | 0.093             | -     | 0.104 |
| A1               | 0.10                 | -    | 0.30  | 0.004             | -     | 0.012 |
| B                | 0.33                 | -    | 0.51  | 0.013             | -     | 0.020 |
| C                | 0.23                 | -    | 0.32  | 0.009             | -     | 0.013 |
| D <sup>(1)</sup> | 15.20                | -    | 15.60 | 0.598             | -     | 0.614 |
| E                | 7.40                 | -    | 7.60  | 0.291             | -     | 0.299 |
| e                | -                    | 1.27 | -     | -                 | 0.050 | -     |
| H                | 10.0                 | -    | 10.65 | 0.394             | -     | 0.419 |
| h                | 0.25                 | -    | 0.75  | 0.010             | -     | 0.030 |
| L                | 0.40                 | -    | 1.27  | 0.016             | -     | 0.050 |
| k                | 0° (min.), 8° (max.) |      |       |                   |       |       |
| ddd              | -                    | -    | 0.10  | -                 | -     | 0.004 |

1. "D" dimension does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per side.

## 8 Revision history

**Table 11. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 03-Sep-2003 | 1        | Initial release.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| 24-Feb-2014 | 2        | <p>Updated <i>Section : Description on page 1</i> (removed “MultiPower-” from “MultiPower-BCD technology”).</p> <p>Added <i>Contents on page 2</i>.</p> <p>Updated <i>Section 1: Block diagram</i> (added section title, numbered and moved <i>Figure 1: Block diagram</i> from page 1 to page 3).</p> <p>Added title to <i>Section 2: Maximum ratings on page 4</i>, added numbers and titles from <i>Table 1: Absolute maximum ratings</i> to <i>Table 3: Thermal data</i>.</p> <p>Added title to <i>Section 3: Pin connections on page 6</i>, added number and title to <i>Figure 2: Pin connections (top view)</i>, renumbered note 1 below <i>Figure 2</i>, added title to <i>Table 4: Pin description</i>.</p> <p>Added title to <i>Section 4: Electrical characteristics on page 8</i>, added title and number to <i>Table 5</i>, renumbered notes 1 to 3 below <i>Table 5</i>. Renumbered <i>Figure 3</i> and <i>Figure 4</i>.</p> <p>Added section numbers to <i>Section 5: Circuit description on page 11</i>, <i>Section 5.1</i> to <i>Section 5.4</i>. Removed “and uC” from first sentence in <i>Section 5.2</i>. Renumbered <i>Table 6</i> and <i>Table 7</i>, added header to <i>Table 6</i>. Renumbered <i>Figure 5</i> to <i>Figure 13</i>. .</p> <p>Added section numbers to <i>Section 6: Application information on page 17</i>, <i>Section 6.1</i> to <i>Section 6.3</i>. Renumbered <i>Table 8</i>, added header to <i>Table 8</i>. Renumbered <i>Figure 14</i> to <i>Figure 29</i>.</p> <p>Updated <i>Section 7: Package information on page 26</i> (added main title and ECOPACK text. Added titles from <i>Table 9: PowerSO36 package mechanical data</i> to <i>Table 11: SO24 package mechanical data</i> and from <i>Figure 30: PowerSO36 package outline</i> to <i>Figure 32: SO24 package outline</i>, reversed order of named tables and figures. Removed 3D figures of packages, replaced 0.200 by 0.020 inch of max. B value in <i>Table 11</i>).</p> <p>Added cross-references throughout document.</p> <p>Added <i>Section 8: Revision history</i> and <i>Table 12</i>.</p> <p>Minor modifications throughout document.</p> |
| 13-Mar-2017 | 3        | <p>Updated <i>Table 8 on page 17</i> (removed C<sub>REF</sub> row).</p> <p>Updated <i>Figure 14 on page 17</i> (replaced by new figure and title).</p> <p>Updated <i>Figure 15 on page 18</i>, <i>Figure 16 on page 19</i>, and <i>Figure 17 on page 20</i> [added “(with reference to 24-pin packages)” to titles].</p> <p>Minor modifications throughout document.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| 03-Oct-2018 | 4        | <p>Removed PowerDIP24 package from the whole document.</p> <p>Removed “T<sub>j</sub>” from <a href="#">Table 2 on page 4</a>.</p> <p>Minor modifications throughout document.</p>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |

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